Study of the correlation between GAE activity and electron transport (XP840)

Field scaling of electron transport change with heating power (XP822)

D. Stutman, L. Delgado, K. Tritz, M. Finkenthal Johns Hopkins University N. Gorelenkov, E. Fredrickson, S. Kaye, E. Mazzucato PPPL

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Motivation: What drives electron transport in flat T_e regimes?



- T_e flattens, central χ_e strongly increases with beam power
- $\chi_e >> D_{imp}$ suggests stochastic electron transport
- Thermal gradients insufficient for any known instability
- Fast ion gradient only source of free-energy
- Is fast ion MHD (*AEs) driving electron transport in NSTX?

Possible relation between electron transport and GAE activity



Correlation seen also in RS L-modes

• GAEs may drive transport of trapped electrons (N. Gorelenkov et al)

Electron transport/GAE relation further studied in XP840



- Experiment:
 - Make AE quiescent H-mode
 - 'Freeze-in' q-profile by preheating
 - Step source B at increasing V_b
- Compare transport at 2-3 t_{beam slowdown}
- Measure GAE δ n/n with high-k system







- Progressive increase in GAE amplitude at ~ constant-q
- Negligible low-f MHD, ELMs

Fast ion distribution likely not much affected by MHD





- Centrally peaked beam ion density
- No anomalies in NPA spectra
- Some global loss possible (metals)

Central electron transport consistently correlates with GAEs



- Ion transport essentially unchanged (≥ neoclassical)
- ~20% TRANSP neutron mismatch (prelim.)
- P_{rad} likely underestimated when metals present (χ_e pre-Li << χ_e post-Li)

AE δ n/n estimated by high-k in interferometry mode



• Local $\delta n/n \leq 10^{-3}$ assuming predicted GAE mode extent

• AE amplitude in L-mode also from reflectometry (N. Crocker talk)

Plasmas with equal P_b at different V_b



Effect of higher magnetic field



- Low-f MHD quiescent, similar q(r) shots at 4.5kG/0.9 MA and 5.5 kG/1.1 MA
- $T_e(0)$ transiently peaks at high B_t ('low rational-q' effect unlikely)
- Later on slightly broader T_e , χ_e profile (prelim.)

Higher GAE frequency might allow T_e peaking at high B_t



- Broad band of higher frequency GAEs(ω_{GAE} ~v_A) at high field
- Resonance with higher energy electrons might allow transient T_e peaking,

- Results broadly consistent with hypothesis of GAE driven electron transport
- Clearer cut demonstration needs higher beam power or RF *AE excitation (present experiments near threshold of highly non-linear effect)
- GAE amplitude in high power H-modes might be relatively high
- Relatively small effect of B_t on electron transport at fixed-q
- $\chi_i \ge \chi^{neo}$ makes unnecessary assuming anomalous ion heating in these XPs
- Power balance with metals present, global fast ions loss, possible issues
- Further study important because of likely implications for burning plasmas

BACKUP SLIDES







ELECTRON HEAT DIFFUSIVITY (CE) VS XB



Contour plot of radial component of fluid velocity at equatorial plane.

dn/n ~1.5e-3 in 130335 (4e-4 line integrated)







r/a





t(s)

